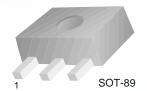


# **FJC1963**

## **Audio Power Amplifier Applications**

- Complement to FJC1308
- High Collector Current
- Low Collector-Emitter Saturation Voltage



1. Base 2. Collector 3. Emitter

## **NPN Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

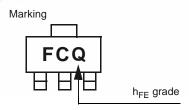
| Symbol           | Parameter                               | Value      | Units |
|------------------|---|------------|-------|
| $V_{CBO}$        | Collector-Base Voltage                  | 50         | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage               | 30         | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage                    | 6          | V     |
| I <sub>C</sub>   | Collector Current (DC)                  | 3          | Α     |
| P <sub>C</sub>   | Power Dissipation(T <sub>C</sub> =25°C) | 0.5        | W     |
| TJ               | Junction Temperature                    | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                     | - 55 ~ 150 | °C    |

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

| Symbol                | Parameter                            | Test Condition                             | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|--|------|------|------|-------|
| BV <sub>CBO</sub>     | Collector-Base Breakdown Voltage     | $I_{C}=50\mu A, I_{E}=0$                   | 50   |      |      | V     |
| BV <sub>CEO</sub>     | Collector-Emitter Breakdown Voltage  | I <sub>C</sub> =1mA, I <sub>B</sub> =0     | 30   |      |      | V     |
| BV <sub>EBO</sub>     | Emitter-Base Breakdown Voltage       | I <sub>E</sub> =50μA, I <sub>C</sub> =0    | 6    |      |      | V     |
| I <sub>CEO</sub>      | Collector Cut-off Current            | V <sub>CE</sub> =40V, V <sub>B</sub> =0    |      |      | 0.5  | μΑ    |
| I <sub>EBO</sub>      | Emitter Cut-off Current              | $V_{EB}$ =5V, $I_C$ =0                     |      |      | 0.5  | μΑ    |
| h <sub>FE</sub>       | DC Current Gain                      | V <sub>CE</sub> =2V, I <sub>C</sub> =0.5A  | 120  |      | 560  |       |
| V <sub>CE</sub> (sat) | Collector-Emitter Saturation Voltage | I <sub>C</sub> =1.5, I <sub>B</sub> =0.15A |      |      | 0.45 | V     |
| V <sub>BE</sub> (sat) | Base-Emitter Saturation Voltage      | I <sub>C</sub> =1.5, I <sub>B</sub> =0.15A |      |      | 1.2  | V     |

## **h**<sub>FE</sub> Classification

| Classification  | Q         | R         | S         |
|-----------------|-----------|-----------|-----------|
| h <sub>FE</sub> | 120 ~ 270 | 180 ~ 390 | 280 ~ 560 |



# **Typical Characteristics**

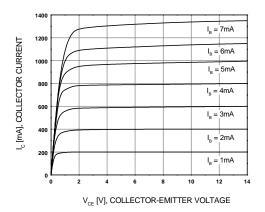


Figure 1. Static Characteristic

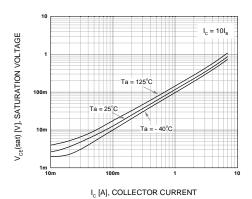


Figure 3. Collector-Emitter Saturation Voltage

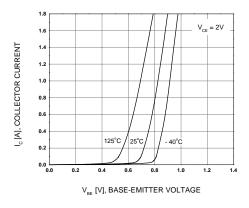


Figure 5. Base-Emitter On Voltage

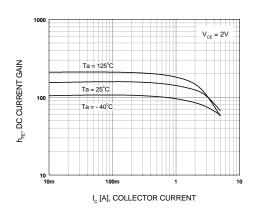


Figure 2. DC current Gain

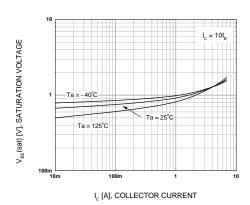


Figure 4. Base-Emitter Saturation Voltage

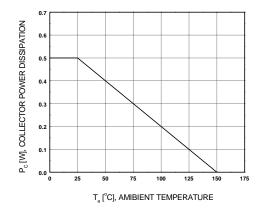
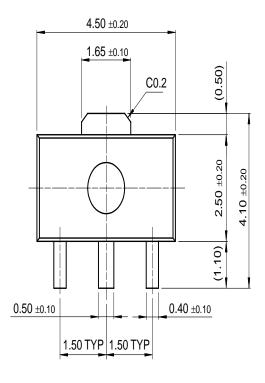


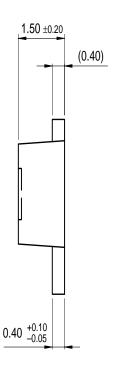
Figure 6. Power Derating

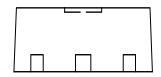
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# **Package Dimensions**

# **SOT-89**







Dimensions in Millimeters

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|--------------------------------------|---------------------|------------------------|--------------------------|-----------------------|
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| Bottomless™                          | FAST <sup>®</sup>   | LittleFET™             | Power247™                | SuperSOT™-3           |
| CoolFET™                             | FASTr™              | MicroFET™              | PowerTrench <sup>®</sup> | SuperSOT™-6           |
| CROSSVOLT™                           | FRFET™              | MicroPak™              | QFET™                    | SuperSOT™-8           |
| DOME™                                | GlobalOptoisolator™ | MICROWIRE™             | QS™                      | SyncFET™              |
| EcoSPARK™                            | GTO™                | MSX™                   | QT Optoelectronics™      | TinyLogic™            |
| E <sup>2</sup> CMOS™                 | HiSeC™              | MSXPro™                | Quiet Series™            | TruTranslation™       |
| EnSigna™                             | $I^2C^{TM}$         | $OCX^{TM}$             | RapidConfigure™          | UHC™                  |
| Across the board. Around the world.™ |                     | OCXPro™                | RapidConnect™            | UltraFET <sup>®</sup> |
| The Power Franchise™                 |                     | OPTOLOGIC <sup>®</sup> | SILENT SWITCHER®         | VCX™                  |
| Programmable Active Droop™           |                     | OPTOPLANAR™            | SMART START™             |                       |

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|--------------------------|---------------------------|---|
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